Data sheet acquired from Harris Semiconductor

September 1998 - Revised October 2000

Octal-Bus Transceiver, Three-State, Non-Inverting

Features

- Buffered Inputs
- Typical Propagation Delay
 - 4ns at $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 50pF$
- Exceeds 2kV ESD Protection per MIL-STD-883, Method 3015
- SCR-Latchup-Resistant CMOS Process and Circuit Design
- Speed of Bipolar FAST™/AS/S with Significantly **Reduced Power Consumption**
- Balanced Propagation Delays
- AC Types Feature 1.5V to 5.5V Operation and Balanced Noise Immunity at 30% of the Supply
- ±24mA Output Drive Current
 - Fanout to 15 FAST™ ICs
 - Drives $\mathbf{50}\Omega$ Transmission Lines

Description

The 'AC245 and 'ACT245 are octal-bus transceivers that utilize Advanced CMOS Logic technology. They are nonbidirectional transceiver-buffers inverting three-state intended for two-way transmission from "A" bus to "B" bus or "B" bus to "A". The logic level present on the direction input (DIR) determines the data direction. When the output enable input (OE) is HIGH, the outputs are in the high-impedance

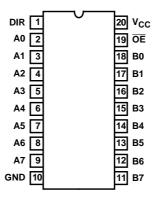
Ordering Information

N	PART IUMBER	TEMP. RANGE (^O C)	PACKAGE
CD54A0	C245F3A	-55 to 125	20 Ld CERDIP
CD74A0	C245E	-55 to 125	20 Ld PDIP
CD74A0	C245M	-55 to 125	20 Ld SOIC
CD74A0	C245SM	-55 to 125	20 Ld SSOP
CD54A	CT245F3A	-55 to 125	20 Ld CERDIP
CD74A0	T245E	-55 to 125	20 Ld PDIP
CD74A	CT245M	-55 to 125	20 Ld SOIC
CD74A0	CT245SM	-55 to 125	20 Ld SSOP

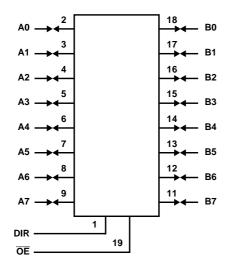
- 1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
- 2. Wafer and die for this part number is available which meets all electrical specifications. Please contact your local TI sales office or customer service for ordering information.

Pinout

CD54AC245, CD54ACT245 (CERDIP) CD74AC245, CD74ACT245 (PDIP, SOIC, SSOP) TOP VIEW



Functional Diagram



TRUTH TABLE

CONTRO	L INPUTS	
ŌĒ	DIR	OPERATION
L	L	B Data to A Bus
L	Н	A Data to B Bus
Н	Х	Isolation

H = High Level, L = Low Level, X = Irrelevant
To prevent excess currents in the High-Z (isolation) modes, all I/O terminals should be terminated with $10k\Omega$ to $1M\Omega$ resistors.

Absolute Maximum Ratings DC Supply Voltage, V_{CC} -0.5V to 6V DC Input Diode Current, I_{IK} DC Output Diode Current, I_{OK}

Thermal Information

Thermal Resistance (Typical, Note 5)	θ_{JA} (oC/W)
E Package	69
M Package	58
SM Package	
Maximum Junction Temperature (Plastic Package)	150 ^o C
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C

Operating Conditions

Temperature Range, T _A	-55°C to 125°C
Supply Voltage Range, V _{CC} (Note 4)	
AC Types	1.5V to 5.5V
ACT Types	4.5V to 5.5V
DC Input or Output Voltage, V _I , V _O	\dots 0V to V _{CC}
Input Rise and Fall Slew Rate, dt/dv	
AC Types, 1.5V to 3V	50ns (Max)
AC Types, 3.6V to 5.5V	20ns (Max)
ACT Types, 4.5V to 5.5V	10ns (Max)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

DC Electrical Specifications

of the device at these or any other	conditions abo	ve those indica	ted in the opera	ational sec	tions of th	is specific	ation is no	ot implied.	•	· ·	·
NOTES:							10				
3. For up to 4 outputs per de	evice, add ±25	mA for each	additional ou	tput.	-8c		10-				
4. Unless otherwise specifie	d, all voltages	are referenc	ed to ground		272						
5. The package thermal imp	edance is cal	culated in acc	ordance with	JESD 51	1-7.	ω .					
				-	m O						
NOTES: 3. For up to 4 outputs per de 4. Unless otherwise specifie 5. The package thermal imp DC Electrical Specifica	ations			4							
			ST ITIONS	Vcc	l	°c	-40	С ТО °С		C TO 5°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
AC TYPES									-	_	-
High Level Input Voltage	V _{IH}	-	-	1.5	1.2	-	1.2	-	1.2	-	V
				3	2.1	-	2.1	-	2.1	-	V
				5.5	3.85	-	3.85	-	3.85	-	V
Low Level Input Voltage	V _{IL}	-	-	1.5	-	0.3	-	0.3	-	0.3	V
				3	-	0.9	-	0.9	-	0.9	V
				5.5	-	1.65	-	1.65	-	1.65	V
High Level Output Voltage	V _{OH}	V _{IH} or V _{IL}	-0.05	1.5	1.4	-	1.4	-	1.4	-	V
			-0.05	3	2.9	-	2.9	-	2.9	-	V
			-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-4	3	2.58	-	2.48	-	2.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5			3.85			-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V

DC Electrical Specifications (Continued)

			TEST CONDITIONS		25	°C		C TO °C		C TO 5°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Low Level Output Voltage	V _{OL}	V _{IH} or V _{IL}	0.05	1.5	-	0.1	-	0.1	-	0.1	V
			0.05	3	-	0.1	-	0.1	-	0.1	V
			0.05	4.5	-	0.1	-	0.1	-	0.1	V
			12	3	-	0.36	-	0.44	-	0.5	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	lį	V _{CC} or GND	-	5.5	-	±0.1	-	±1	-	±1	μА
Three-State Leakage Current	l _{OZ}	V _{IH} or V _{IL} V _O = V _{CC} or GND	-	5.5	-	±0.5	3_	±5	-	±10	μА
Quiescent Supply Current MSI	Icc	V _{CC} or GND	0	5.5	-ðic	8	127	80	-	160	μА
ACT TYPES				20 4	772	- 1	A 1.				
High Level Input Voltage	V _{IH}	-		4.5 to 5.5	2	40.	2	-	2	-	V
Low Level Input Voltage	V _{IL}		11	4.5 to 5.5		0.8	-	0.8	-	0.8	V
High Level Output Voltage	V _{OH}	V _{IH} or V _{IL}	-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
	3		-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V
Low Level Output Voltage	V _{OL}	V _{IH} or V _{IL}	0.05	4.5	-	0.1	-	0.1	-	0.1	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	ı	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	ı	-	ı	-	-	1.65	V
Input Leakage Current	II	V _{CC} or GND	-	5.5	-	±0.1	-	±1	-	±1	μА
Three-State or Leakage Current	l _{OZ}	V _{IH} or V _{IL} V _O = V _{CC} or GND	-	5.5	-	±0.5	-	±5	-	±10	μА
Quiescent Supply Current MSI	Icc	V _{CC} or GND	0	5.5	-	8	-	80	-	160	μА
Additional Supply Current per Input Pin TTL Inputs High 1 Unit Load	Δl _{CC}	V _{CC} -2.1	-	4.5 to 5.5	-	2.4	-	2.8	-	3	mA

- 6. Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.
- 7. Test verifies a minimum 50Ω transmission-line-drive capability at 85° C, 75Ω at 125° C.

ACT Input Load Table

INPUT	UNIT LOAD
An, Bn	0.83
ŌĒ	0.64
DIR	0.25

NOTE: Unit load is ΔI_{CC} limit specified in DC Electrical Specifications Table, e.g., 2.4mA max at 25°C.

$\textbf{Switching Specifications} \ \, \textbf{Input } t_{r}, \, t_{f} = 3 \text{ns}, \, C_{L} = 50 \text{pF (Worst Case)}$

			-40	°C TO 85	°C	-55			
PARAMETER	SYMBOL	V _{CC} (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
AC TYPES									
Propagation Delay,	t _{PLH} , t _{PHL}	1.5	-	-	96	-	-	106	ns
Data to Output		3.3 (Note 9)	3.2	-	10.8	3	-	11.9	ns
		5 (Note 10)	2.2	-	7.7	2.1	-	8.5	ns
Propagation Delay,	t _{PLZ} , t _{PHZ}	1.5	-	36	159	n.	-	175	ns
Output Disable to Output		3.3	4.7	カード	15.9	4.4	-	17.5	ns
		5	3.7	~0	12.7	3.5	-	14	ns
Propagation Delay,	t _{PZL} , t _{PZH}	1.5	1		159	-	-	175	ns
Output Enable to Output		3.3	5.6	-	19	5.3	-	21	ns
		5	3.7	-	12.7	3.5	-	14	ns
Minimum (Valley) V _{OH} During Switching of Other Outputs (Output Under Test Not Switching)	V _{OHV} See Figure 1	5	-	4 at 25 ⁰ C	-	-	4 at 25°C	-	V
Maximum (Peak) V _{OL} During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP} See Figure 1	5	-	1 at 25 ⁰ C	-	-	1 at 25 ⁰ C	-	V
Three-State Output Capacitance	CO	-	-	15	-	-	15	-	pF
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C _{PD} (Note 11)	-	-	57	-	-	57	-	pF
ACT TYPES	Į.	!	<u>I</u>						
Propagation Delay, Data to Output	t _{PLH} , t _{PHL}	5 (Note 10)	2.7	-	9.1	2.5	-	10	ns
Propagation Delay, Output Disable to Output	t _{PLZ} , t _{PHZ}	5	3.7		12.7	3.5		14	ns
Propagation Delay, Output Enable to Output	t _{PZL} , t _{PZH}	5	3.8		13.1	3.6		14.4	ns
Minimum (Valley) V _{OH} During Switching of Other Outputs (Output Under Test Not Switching)	V _{OHV} See Figure 1	5	-	4 at 25°C	-	-	4 at 25°C	-	V
Maximum (Peak) V _{OL} During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP} See Figure 1	5	-	1 at 25 ^o C	-	-	1 at 25 ^o C	-	V

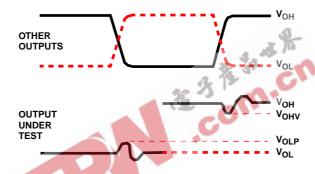
Switching Specifications Input t_p , t_f = 3ns, C_L = 50pF (Worst Case) (Continued)

			-40°C TO 85°C		-55°C TO 125°C				
PARAMETER	SYMBOL	V _{CC} (V)	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Three-State Output Capacitance	CO	-	-	15	-	-	15	-	pF
Input Capacitance	Cl	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C _{PD} (Note 11)	-	-	57	-	-	57	-	pF

NOTES:

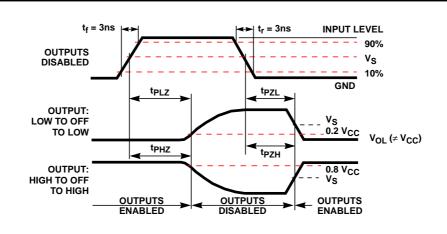
- 8. Limits tested 100%
- 9. 3.3V Min is at 3.6V, Max is at 3V.
- 10. 5V Min is at 5.5V, Max is at 4.5V.

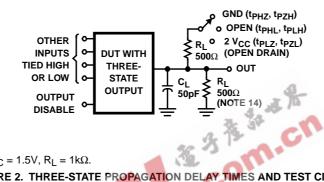
11. C_{PD} is used to determine the dynamic power consumption per channel. AC: $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ ACT: $P_D = V_{CC}^2 f_i (C_{PD} + C_L) + V_{CC} \Delta I_{CC}$ where f_i = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.



- 12. Input pulses have the following characteristics: PRR \leq 1MHz, t_r = 3ns, SKEW 1ns.
- 13. R.F. fixture with 700MHz design rules required. IC should be soldered into test board and bypassed with $0.1 \mu F$ capacitor. Scope and probes require 700MHz bandwidth.

FIGURE 1. SIMULTANEOUS SWITCHING TRANSIENT WAVEFORMS





NOTE:

14. For AC Series only: When V_{CC} = 1.5V, R_L = 1k Ω .

FIGURE 2. THREE-STATE PROPAGATION DELAY TIMES AND TEST CIRCUIT

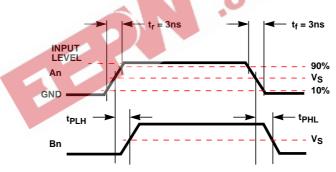
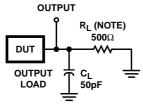


FIGURE 3. PROPAGATION DELAY TIMES



NOTE: For AC Series Only: When V_{CC} = 1.5V, R_L = 1k Ω .

	AC	ACT
Input Level	V _{CC}	3V
Input Switching Voltage, V _S	0.5 V _{CC}	1.5V
Output Switching Voltage, V _S	0.5 V _{CC}	0.5 V _{CC}

FIGURE 4. PROPAGATION DELAY TIMES





www.ti.com 6-Dec-2006

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD54AC245F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD54ACT245F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD74AC245E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74AC245EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74AC245M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC245M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC245M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC245ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC245SM	OBSOLETE	SSOP	DB	20	25.	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC245SM96	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC245SM96E4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT245E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74ACT245EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74ACT245M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT245M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT245M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT245ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT245SM	OBSOLETE	SSOP	DB	20		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT245SM96	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT245SM96E4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

6-Dec-2006

for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

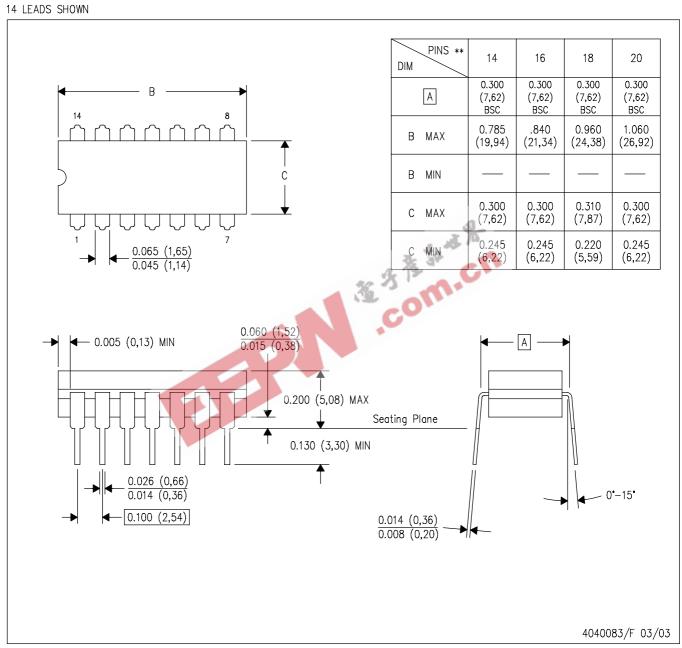
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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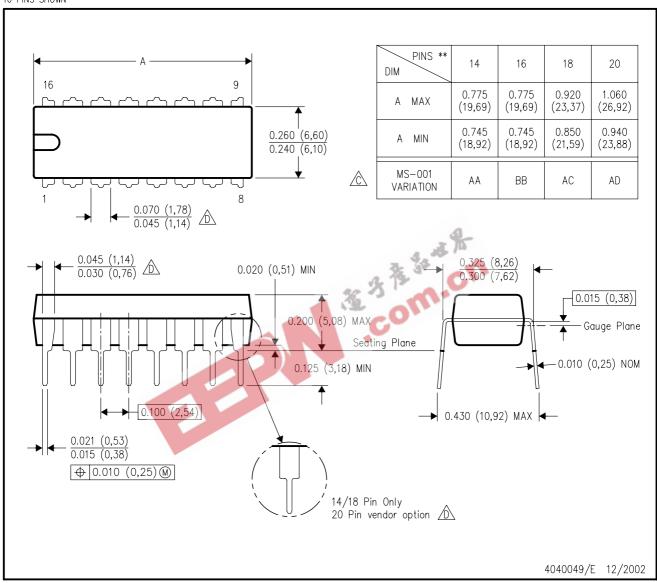


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

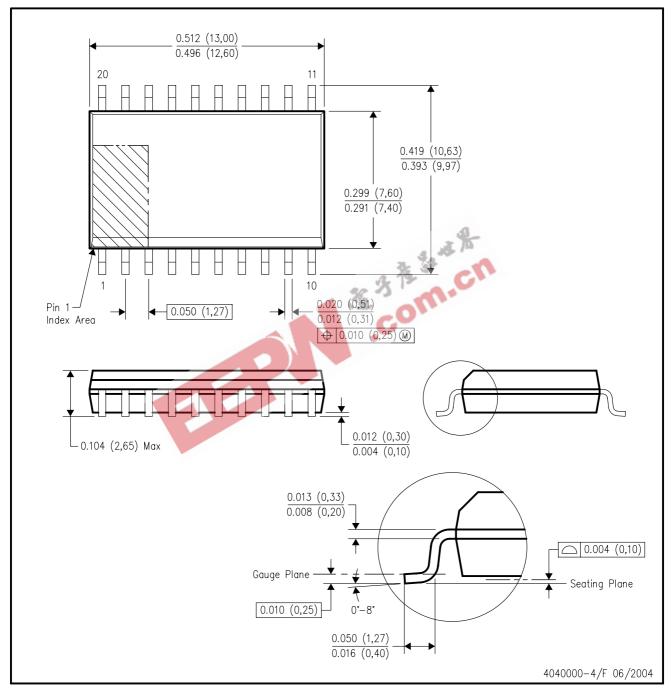


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



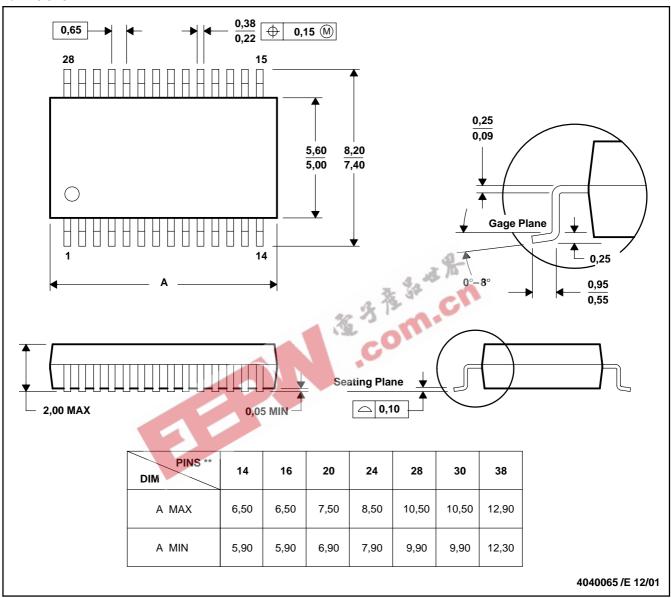
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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